

VS-12TQ035-M3, VS-12TQ040-M3, VS-12TQ045-M3

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Vishay Semiconductors

COMPLIANT

HALOGEN

FREE

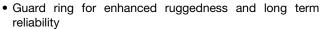
High Performance Schottky Rectifier, 15 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	15 A						
V_{R}	35 V, 40 V, 45 V						
V _F at I _F	0.50 V						
I _{RM} typ.	70 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	16 mJ						
Package	TO-220AC 2L						
Circuit configuration	Single						

FEATURES

- 150 °C T_J operation
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

The VS-12TQ... Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	15	Α				
V _{RRM}	Range	35 to 45	V				
I _{FSM}	t _p = 5 μs sine	990	Α				
V _F	15 A _{pk} , T _J = 125 °C	0.50	V				
T_J	Range	-55 to +150	°C				

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-12TQ035-M3 VS-12TQ040-M3 VS-12TQ045-M3 UNITS								
Maximum DC reverse voltage	V_R	35	40	45	V			
Maximum working peak reverse voltage	V_{RWM}	33	40	45	v			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS			
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 120 °C	15				
Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load	990	Α		
surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	250			
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2.4 \text{A}, L = 5.5 \text{mH}$		16	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		2.4	Α		



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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TES	TEST CONDITIONS				
Maximum forward voltage drop See fig. 1		15 A	T _{.1} = 25 °C	0.56			
	V _{FM} ⁽¹⁾	30 A	1J = 25 C	0.71	٧		
		15 A	T _{.1} = 125 °C	0.50			
		30 A	1J = 125 C	0.64	i		
Maximum rayaya laakaga ayyyant	I _{RM} ⁽¹⁾	T _J = 25 °C	V Poted V	1.75	mA		
Maximum reverse leakage current		T _J = 125 °C	$V_R = Rated V_R$	110			
Typical reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	70	mA		
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		900	pF		
Typical series inductance	L _S	Measured lead to le	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs			

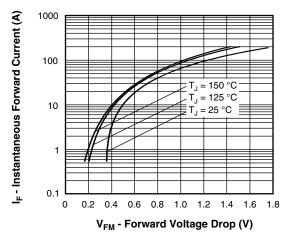
Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	YMBOL TEST CONDITIONS		UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	2.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50	°C/VV			
Anarovimoto weight				2	g			
Approximate weight				0.07	OZ.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	($lbf \cdot in$)			
Marking device				12T0	2035			
			Case style TO-220AC 2L	12T0	2040			
				12T0	12TQ045			

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1000 T_{.1} = 150 °C 100 I_R - Reverse Current (mA) T₁ = 125 °C 10 $T_J = 100 \, ^{\circ}C$ °C = 50 °C 0.01 $T_J = 25 \, {}^{\circ}\overline{C}$ 0.001 5 15 20 25 30 35 40 0 10 V_R - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

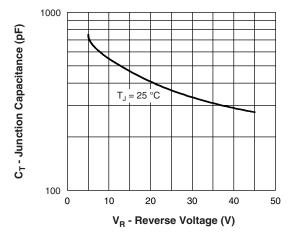


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

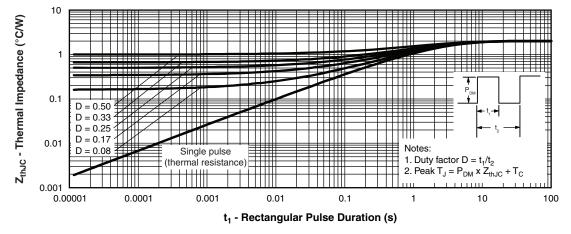


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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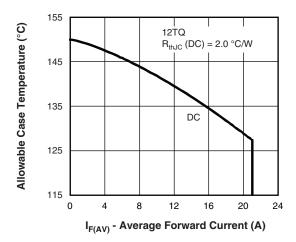


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

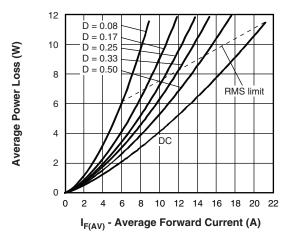


Fig. 6 - Forward Power Loss Characteristics

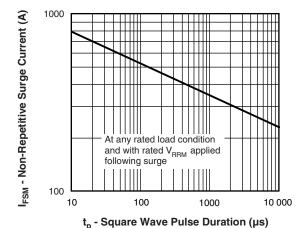


Fig. 7 - Maximum Non-Repetitive Surge Current

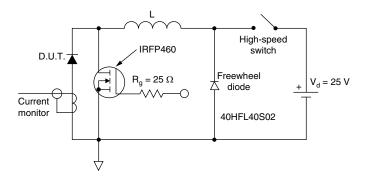


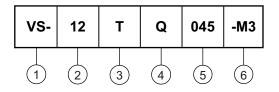
Fig. 8 - Unclamped Inductive Test Circuit

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ORDERING INFORMATION TABLE





1 - Vishay Semiconductors product

2 - Current rating (15 A)

3 - Package:

T = TO-220

4 - Schottky "Q" series

035 = 35 V 040 = 40 V

5 - Voltage ratings

045 = 45 V

6 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-12TQ035-M3	50	Antistatic plastic tubes						
VS-12TQ040-M3	50	Antistatic plastic tubes						
VS-12TQ045-M3	50	Antistatic plastic tubes						

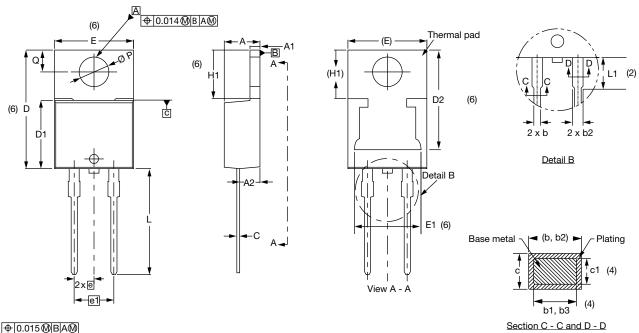
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?96156</u>						
Part marking information	www.vishay.com/doc?95391					

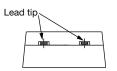


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TO-220AC 2L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIM	IETERS	INCHES		NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355				•	•			

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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